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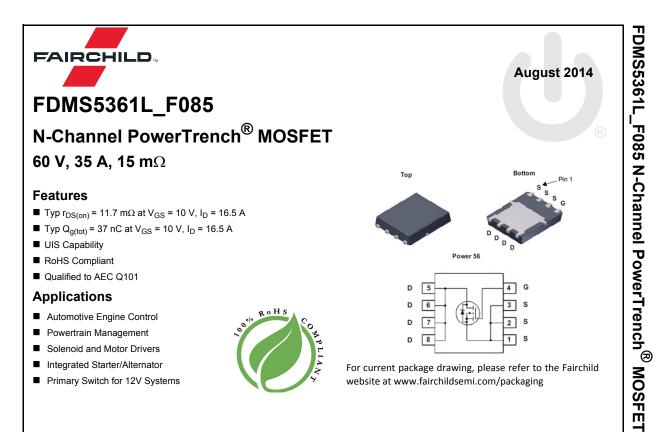


ON Semiconductor®

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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

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MOSFET Maximum Ratings T₁ = 25°C unless otherwise noted.

Symbol	Parameter		Ratings	Units
V _{DSS}	Drain to Source Voltage		60	V
V _{GS}	Gate to Source Voltage		±20	V
	Drain Current - Continuous (V _{GS} =10) (Note 1)	T _C =25°C	35	•
D	Pulsed Drain Current	T _C = 25°C	See Figure4	Α
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	82	mJ
6	Power Dissipation		75	W
PD	Derate above 25°C		0.5	W/ºC
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case		2.0	°C/W
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	50	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMS5361L	FDMS5361L_F085	Power 56	13"	12mm	3000 units

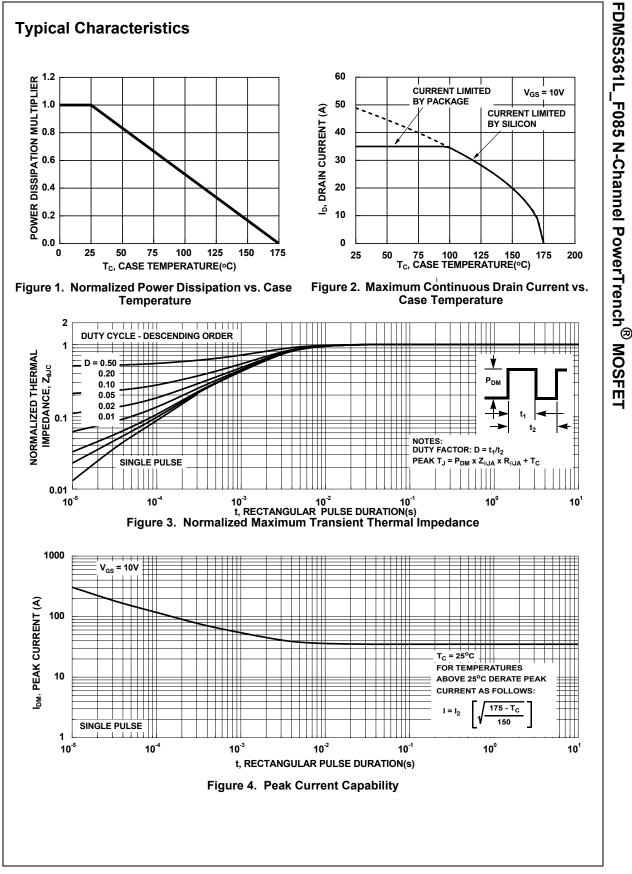
Notes:

1: Current is limited by junction temperature.

2: Starting T_J = 25°C, L = 0.21mH, I_{AS} = 28A, V_{DD} = 60V during inductor charging and V_{DD} = 0V during time in avalanche. 3: $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder ⁴⁰⁰ mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta JA}$ is determined by the user's board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

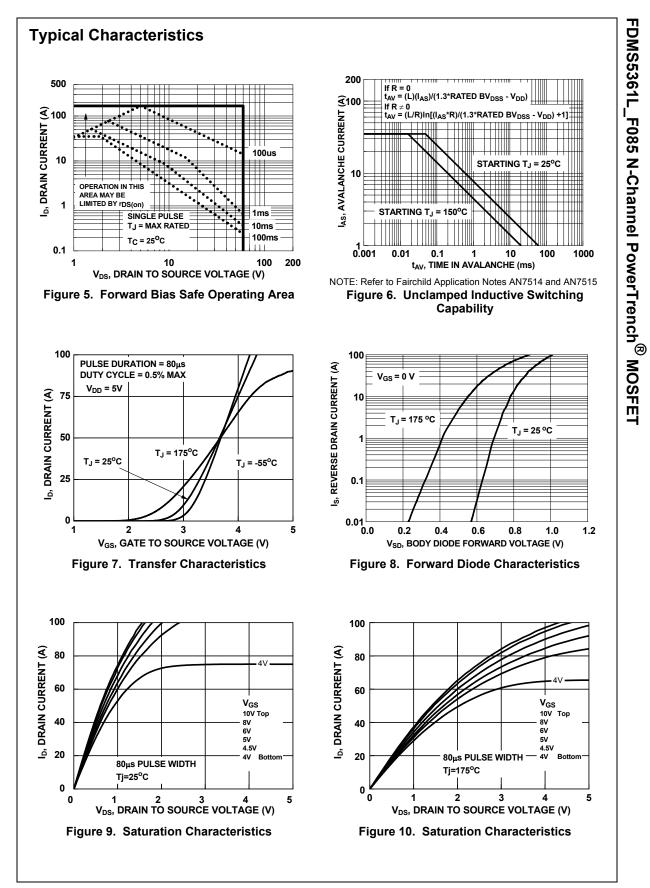
Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Units
Off Cha	aracteristics						
B _{VDSS}	Drain to Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0V		60	-	-	V
		V _{DS} =60V,		-	-	1	μA
IDSS	Drain to Source Leakage Current	V _{GS} = 0V	$T_{J} = 175^{\circ}C(Note 4)$	-	-	1	mA
I _{GSS}	Gate to Source Leakage Current	V _{GS} = ±20V		-	-	±100	nA
On Cha	racteristics						
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D	= 250μA	1.0	1.84	3.0	V
R _{DS(on)}			$T_{J} = 25^{\circ}C$	-	11.7	15	mΩ
		V _{GS} = 10V	$T_{\rm J} = 175^{\rm o} C({\rm Note} \ 4)$	-	24.5	30	mΩ
	Drain to Source On Resistance	I _D = 16.5A,	T _J = 25 ^o C	-	14.6	18	mΩ
		V _{GS} = 4.5V	$T_{J} = 175^{\circ}C(Note 4)$	-	29.5	34	mΩ
-	ic Characteristics				1		
C _{iss}	Input Capacitance	V _{DS} = 25V, V _{GS} = 0V, f = 1MHz		-	1980	-	pF
C _{oss}	Output Capacitance			-	176	-	pF
C _{rss}	Reverse Transfer Capacitance			-	93	-	pF
Rg	Gate Resistance	f = 1MHz		-	1.6	-	Ω
Q _{g(ToT)}	Total Gate Charge at 10V			-	37	44	nC
Q _{g(th)}	Threshold Gate Charge			-	3.6	5	nC
Q _{gs}	Gate to Source Gate Charge			-	5.5	-	nC
Q _{gd}	Gate to Drain "Miller" Charge			-	7.3	-	nC
Switchi	Turn-On Time				_	30	ns
t _{d(on)}	Turn-On Delay	V_{DD} = 30V, I_D = 16.5A, V_{GS} = 10V, R_{GEN} = 6 Ω		-	16	-	ns
t _r	Rise Time			-	10	-	ns
t _{d(off)}	Turn-Off Delay			-	52	-	ns
t _f	Fall Time			-	8	-	ns
t _{off}	Turn-Off Time			-	-	67	ns
	ource Diode Characteristics				1	1	
V _{SD}	Source to Drain Diode Voltage	I _{SD} = 16.5A, V _{GS} = 0V		-	-	1.25	V
t _{rr}	Reverse Recovery Time	I _F = 16.5A, dI _{SD} /dt = 100A/μs, V _{DD} =48V		-	28	32	ns
Q _{rr}	Reverse Recovery Charge			-	25	33	nC

FDMS5361L_F085 N-Channel PowerTrench[®] MOSFET

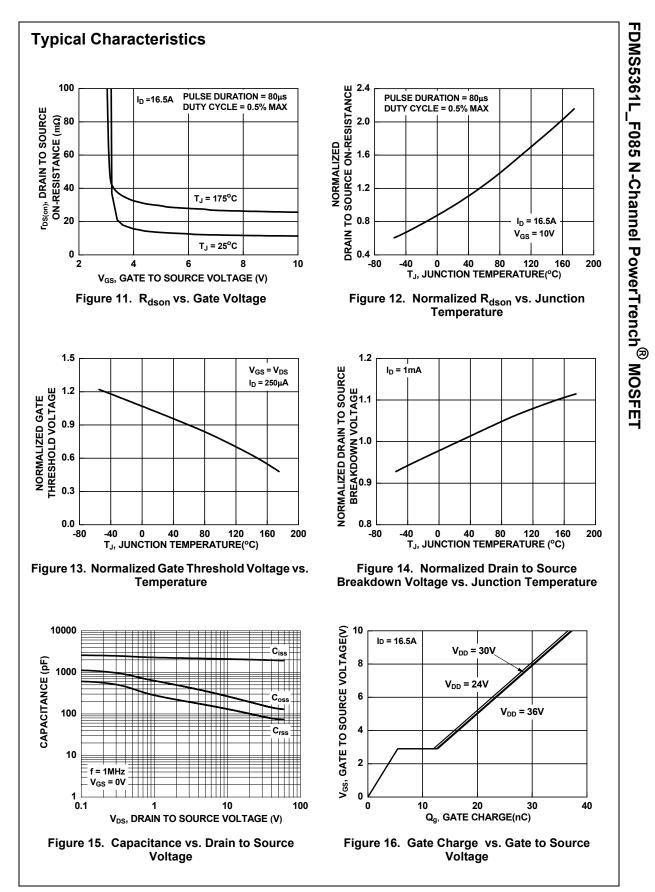


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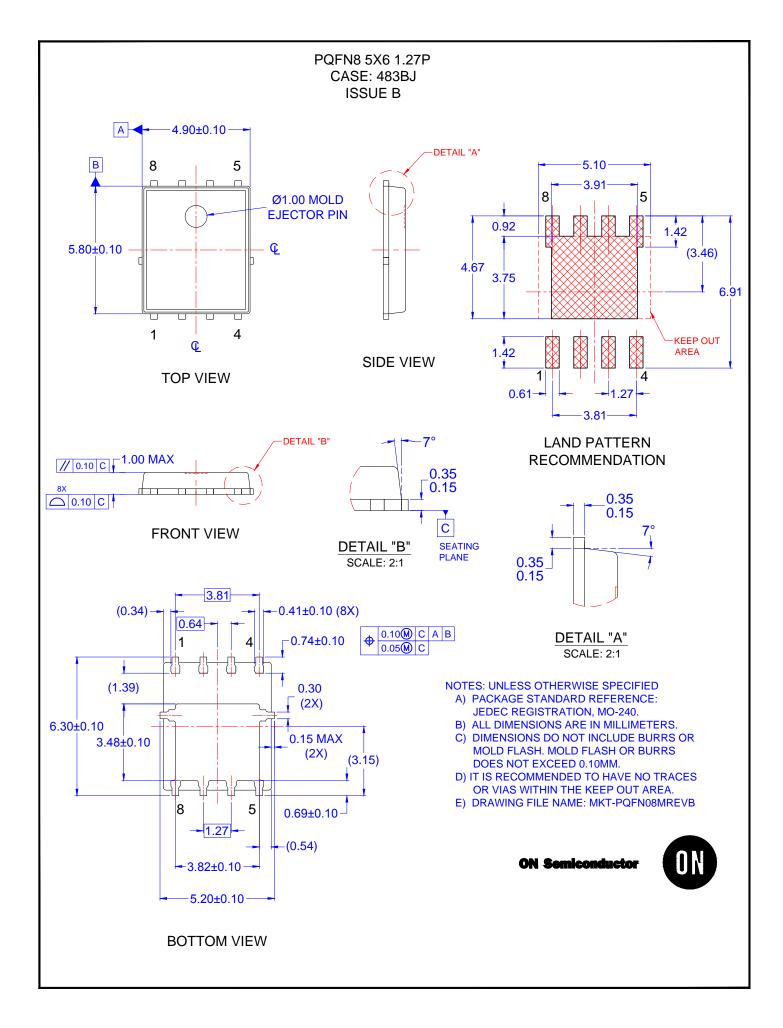
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